

United States Patent [19]

Nishizawa

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[54] **PHOTODIODE**

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[73] Assignee: **Sumitomo Electric Industries, Ltd., Osaka, Japan**

[**] Term: **14 Years**

[21] Appl. No.: **619,755**

[22] Filed: **Jun. 12, 1984**

[30] **Foreign Application Priority Data**

Dec. 16, 1983 [JP] Japan 58-54295

[52] U.S. Cl. **D13/99**

[58] Field of Search D13/40, 41, 99;
174/52 R, 52 PE, 52 S; 357/30, 56, 58, 72, 74

[56] **References Cited**

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[57] **CLAIM**

The ornamental design for photodiode, as shown and described.

DESCRIPTION

FIG. 1 is a front, top and right side perspective view of a photodiode showing my new design;
FIG. 2 is a front elevational view thereof;
FIG. 3 is a rear elevational view thereof;
FIG. 4 is a top plan view thereof; and
FIG. 5 is a right side elevational view thereof; the opposite side being a mirror image thereof.

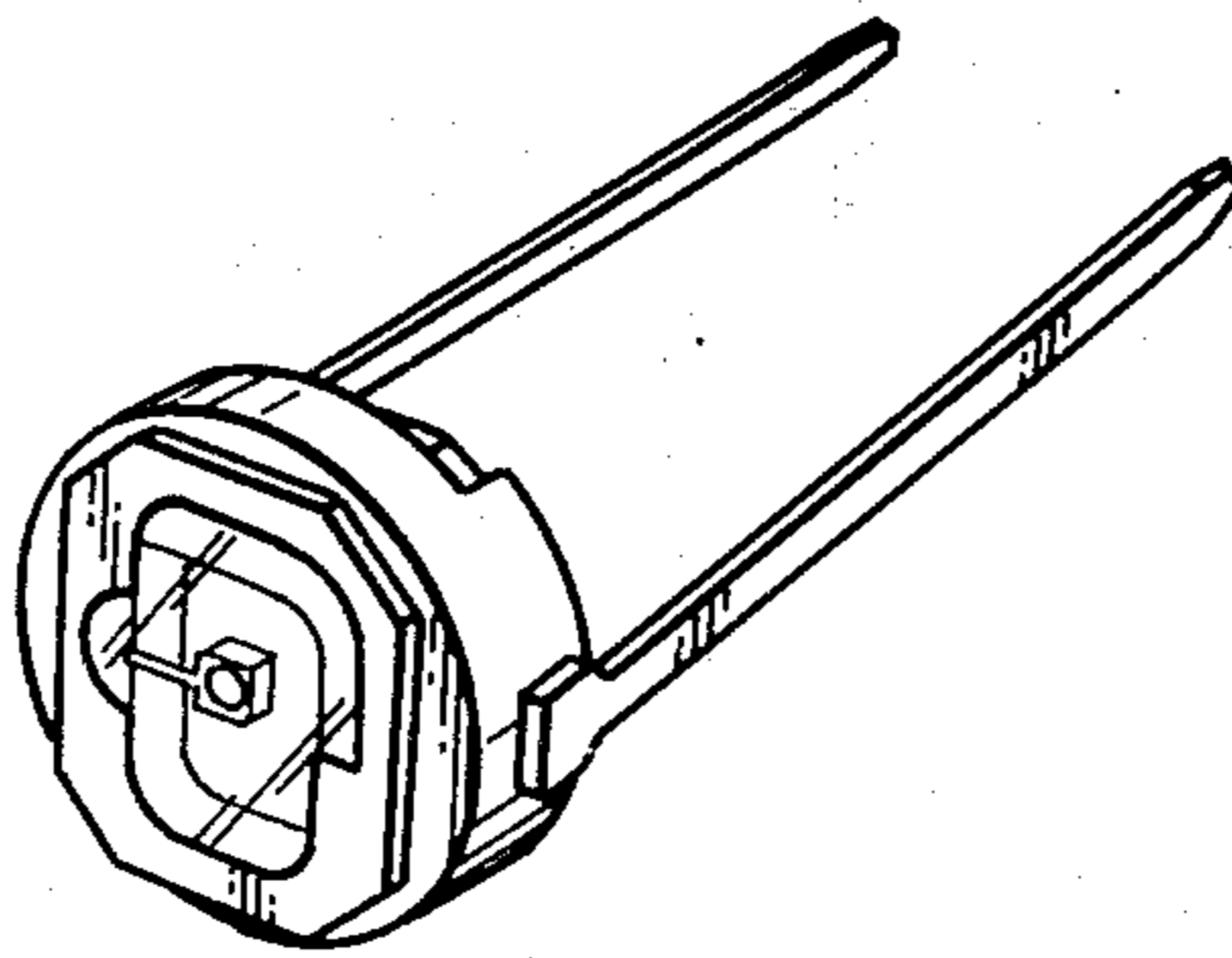


Fig. 1

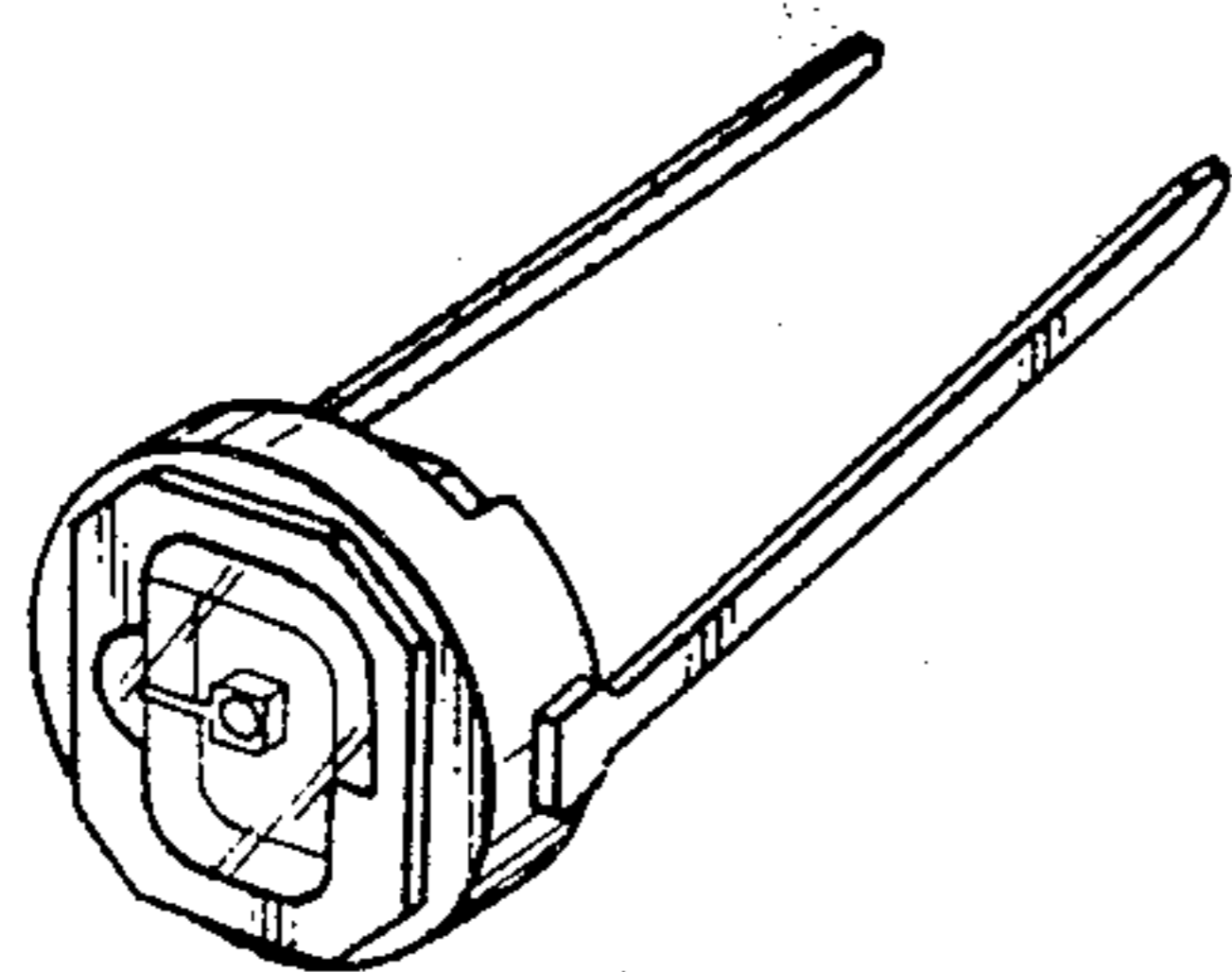


Fig. 2

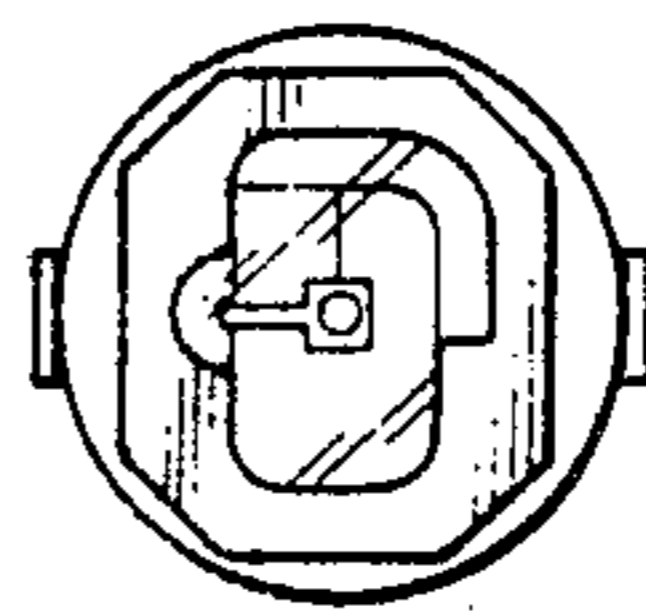


Fig. 3

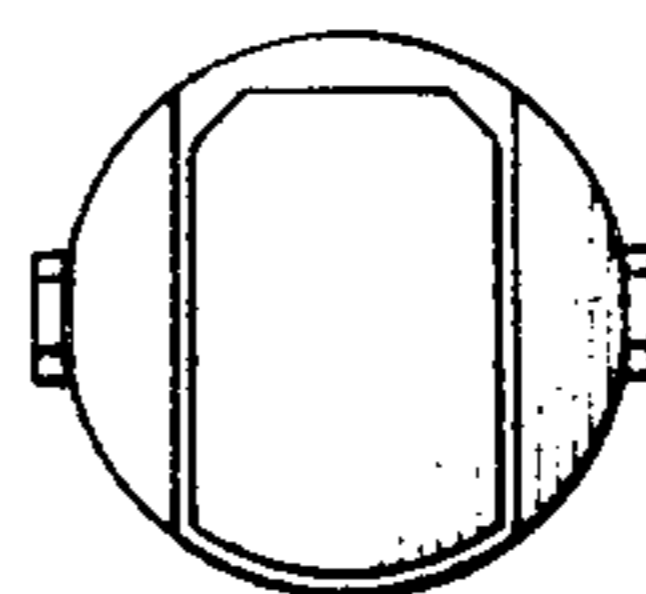


Fig. 4

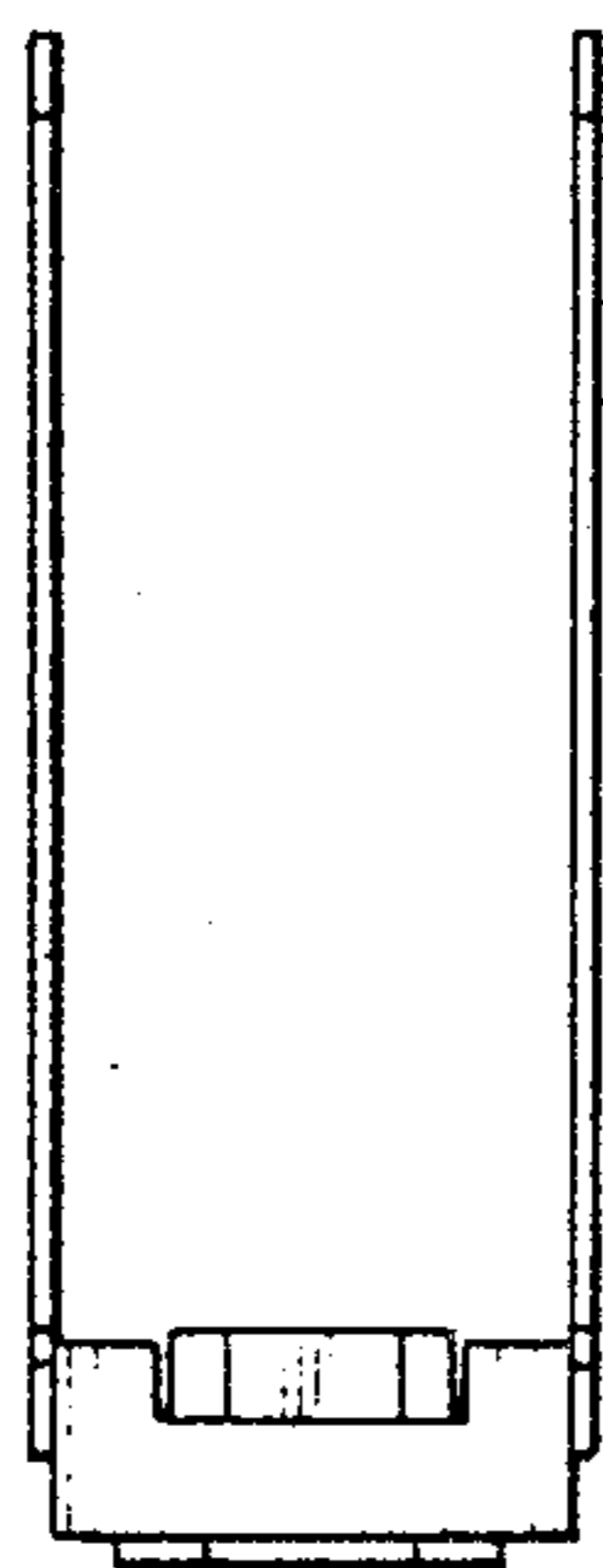


Fig. 5

